

BA	AL	"Molecular beam epitaxy of strained Si <sub>1-x</sub> Ge <sub>x</sub> layers on patterned substrates" 1993-06-01, Journal of Crystal Growth, North-Holland Publishing Co., Vol. 130, nos. 3/4, pages 611-616, Bugiel et al.	
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EXAMINER		/Bac Au/	DATE CONSIDERED 05/23/2006
<p>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</p>			